

零件承认书

SPECIFICATION FOR APPROVAL

客户名称： 0110

客户料号：

增益型号：

规格描述： ZEPIM303015T 小一体成型电感系列规格书

日 期： 2022/05/08

版 本： A

增益签核：

制订	审核	核准
夏琳		李万

客户签核：

工程	审核	核准



东莞市增益实业有限公司

地址：东莞市塘厦镇林村塘厦大道北552号

电话：0769-87321000

传真：0769-87891229

物料类型： 小一体成型电感

日 期： 2022/05/08

版 本： A



◆特征:

Features:

- 1.1 Metal material for large current and low loss.
- 1.2 High performance (Isat) realized by metal dust core.
- 1.3 Low loss realized with low Rdc.
- 1.4 Closed magnetic circuit design reduces leakage flux.
- 1.5 Vinyl thermal spray, better surface compactness.
- 1.6 Environmental requirements must comply with the QESP-44 document
- 1.7 100% lead (Pb) free meet RoHS2.0 and Halogen ,
Reach and other legal and regulatory requirements standard.

◆用途:

Applications:

- 2.1 DC/DCconverters.
- 2.2 Pad,Smartphone.
- 2.3 Portablegamingdevices,Smartwear,Wi-Fi module.
- 2.4 Notebooks,VR,AR.
- 2.5 LCDdisplays,HDDs,DVCs,DSCs,etc.
- 2.6 Basebandpowersupply,Amplifier,Powermanagement,
Modulepowersupply,Camerapowermanageme.

◆产品型号:

ProductIdentification:

ZEPIM303015T1R0MLF

①②③④⑤⑥⑦

- ①Series Name: Mini Molding Power Inductors
- ② External Dimensions(L×W):3030=3.0*3.0 mm
- ③External Dimensions(H):15=1.5 mm
- ④package:T=编带
- ⑤nductance value:1R0=1.0uH
- ⑥Tolerance:M=±20%
- ⑦Lead free products:环保产品

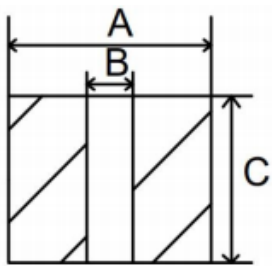
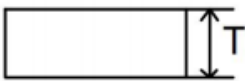
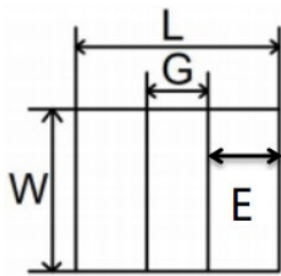


◆产品外观尺寸：

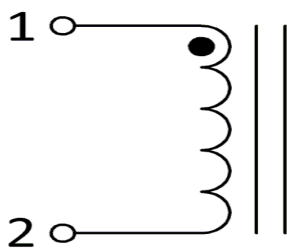
Shape and Dimensions (dimensions are in mm)：

Outline Dimensions

Recommend Land Pattern Dimensions



SCHEMATIC

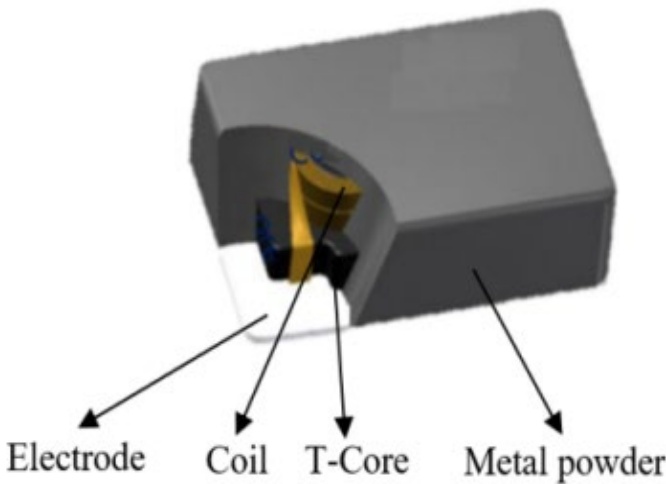


Units:mm

Series	L	G/Typ	W	E	T	A/Typ	B/Typ	C/Typ
ZEP1M303015T	3.0±0.1	0.9±0.2	3.0±0.1	1.00±0.2	1.50Max.	3.00	0.90	3.00

◆产品构造：

Material List



◆环境：

Environmental Data:

●工作温度：-55℃至+125℃
(包括线圈自身温升)

●Operating Temperature:-55℃
to +125℃ (Including coil self-
temperature rise)



◆ Electrical Characteristics电气性能

ZEPIM303015T Series

P/N	L0 (μH) @ (0A) 1MHz	Rdc (mΩ)		Heat rating current		Saturation current	
		Typical	Max	Typical	Max	Typical	Max
ZEPIM303015TR15MLF	0.15	5.00	6.00	12.20	11.20	16.20	15.20
ZEPIM303015TR47MLF	0.47	9.00	11.00	9.20	8.20	10.20	9.20
ZEPIM303015T1R0MLF	1.00	18.00	22.00	6.20	5.70	7.20	6.70
ZEPIM303015T1R5MLF	1.50	22.00	26.00	8.20	7.70	6.20	5.70
ZEPIM303015T2R2MLF	2.20	42.00	50.00	4.70	4.20	5.20	4.70
ZEPIM303015T4R7MLF	4.70	87.00	104.00	3.70	3.20	4.20	3.70
ZEPIM303015T6R8MLF	6.80	160.00	180.00	2.70	2.20	3.70	3.20
ZEPIM303015T100MLF	10.00	185.00	215.00	2.20	1.70	3.00	2.70
ZEPIM303015T220MLF	22.00	580.00	700.00	1.40	1.20	1.80	1.40

Test remarks

Note 1.: All test data is referenced to 25 °C ambient.

Note 2.: Test Condition:1MHz, 1.0Vrms.

Note 3.: Irms:DC current (A) that will cause an approximate ΔT of 40 °C.

Note 4.: Isat:DC current (A) that will cause L0 to drop approximately 30%.

Note 5.: Operating Temperature Range -55°C to + 125°C.

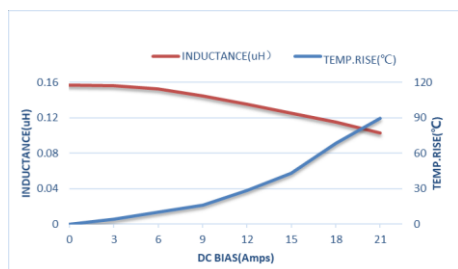
Note 6.: The part temperature (ambient + temp rise) should not exceed 125 under °C the worst case operating conditions.
Circuit design, component placement, PCB trace size and thickness, airflow and other cooling provision all affect the part temperature. Part temperature should be verified in the end application.

Note 7.: The rated current as listed is either the saturation current or the heating current depending on which value is lowe.

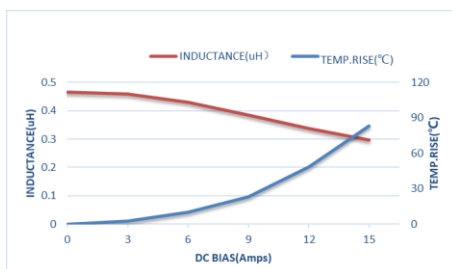


Characteristic curve 特性曲线

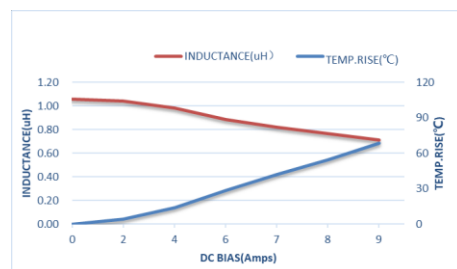
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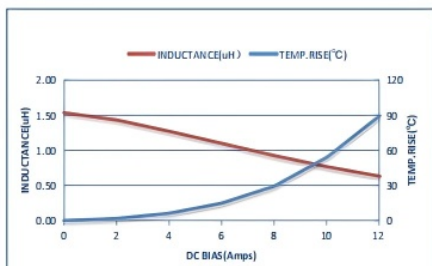
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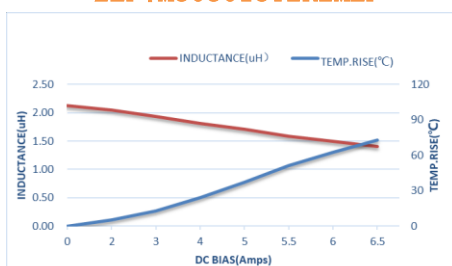
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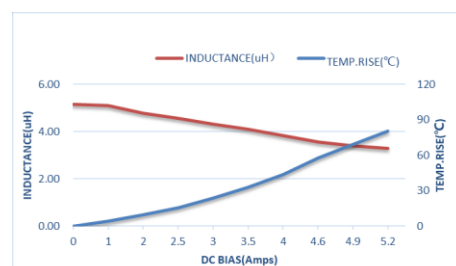
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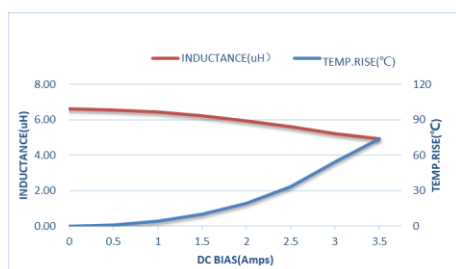
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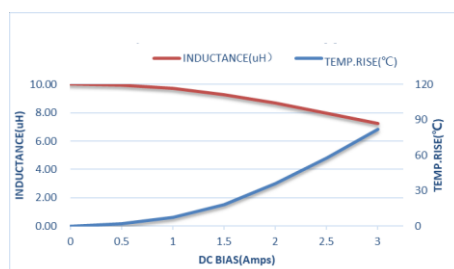
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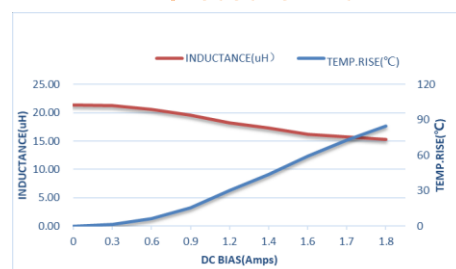
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ZEPIM303015T100MLF

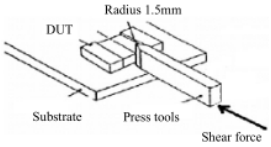
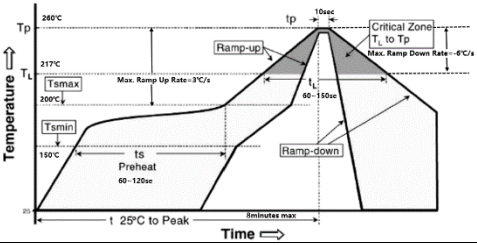
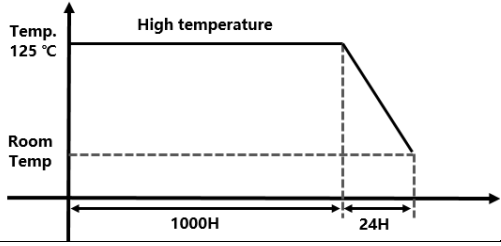
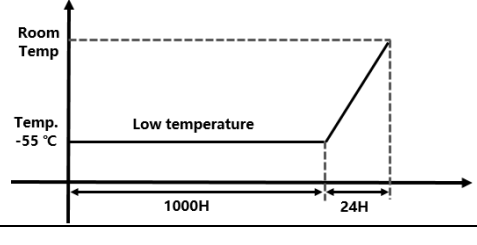


ZEPIM303015T220MLF



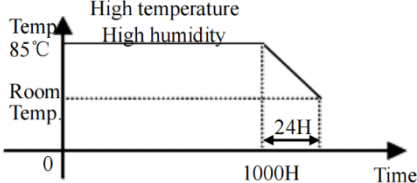
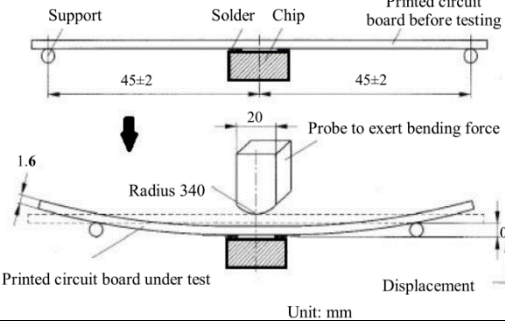


◆ 可靠性测试

No.	Item	Requirements	Test Methods and Remarks	Reference	Sample Size
1	Solderability	(1) No case deformation or change in appearance. (2) Terminal area must have 95% min. Solder coverage.	① Temperature: $245 \pm 5^{\circ}\text{C}$. ② Solder Composition: Sn/Ag3.0/Cu0.5(Pb-Free). ③ Sample immersion tin furnace $5 \pm 0.5\text{s}$.	AEC-Q200 (J-STD 002)	32
2	Adhesion of teral electrode	(1) Strong bond between the pad and the core, without come off PCB.	① Preconditioning: 245°C Reflow 3 times ② Inductors shall be subjected to $(260+0/-5^{\circ}\text{C})^{\circ}\text{C}$ for $(10 \pm 5)\text{s}$ Soldering in the base whit 0.3mm solder. ③ Aplombelectrode way plus tax 12 N for (10 ± 1) seconds. 	AEC-Q200 (AEC-Q200-006)	32
3	Reflow test	(1) No physical damage. (2) $ \Delta L0/L0 \leq 10\%$	① The peak temperature: $260+0/-5^{\circ}\text{C}$. ② Reflow: 3 times. ③ Temperature curve is as below 	AEC-Q200 (MIL-STD-202 Method 210)	32
4	High temperature	(1) No physical damage. (2) $ \Delta L0/L0 \leq 10\%$	① Preconditioning: Bake at $125+5^{\circ}\text{C}$ for $24 \pm 0.5\text{H}$, 245°C Reflow 3 times ② Temperature: $125 \pm 2^{\circ}\text{C}$. ③ Time : 1000 hours. ④ Measurement at 24 ± 4 hours after test conclusion 	AEC-Q200 (MIL-STD -202 Method 108)	77
5	Low temperature	(1) No physical damage. (2) $ \Delta L0/L0 \leq 10\%$	① Preconditioning: Bake at $125+5^{\circ}\text{C}$ for $24 \pm 0.5\text{H}$, 245°C Reflow 3 times ② Temperature: $-55 \pm 2^{\circ}\text{C}$. ③ Time : 1000 hours. ④ Measurement at 24 ± 4 hours after test conclusion 	JESD22-A119A	77
6	Thermal shock	(1) No physical damage. (2) $ \Delta L0/L0 \leq 10\%$	① Preconditioning: Bake at $125+5^{\circ}\text{C}$ for $24 \pm 0.5\text{H}$, 245°C Reflow 3 times ② Repeat 500 cycle as follow : ($-55 \pm 2^{\circ}\text{C}$, $30 \pm 3\text{minutes}$) 、 (Room temperature, 5 minutes)、 ($+125 \pm 2^{\circ}\text{C}$, $30 \pm 3\text{minutes}$)、 (Room temperature, 5 minutes) ③ Measurement at 24 ± 4 hours after test conclusion	MIL-STD -202 Method 107	77



◆ 可靠性测试

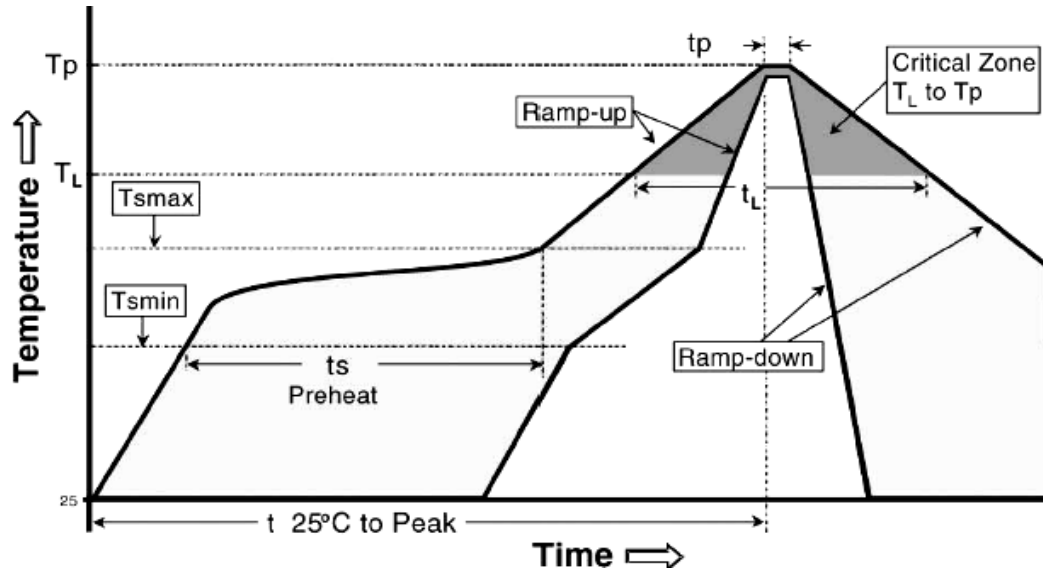
No.	Item	Requirements	Test Methods and Remarks	Reference	Sample Size
7	Resistance to Soldering Heat	(1) No physical damage. (2) $ \Delta L_0/L_0 \leq 10\%$	① Solder Composition: Sn/Ag3.0/Cu0.5(Pb-Free). ② Solder Temperature: $260 \pm 5^\circ\text{C}$. ③ Immersion Time: $10 \pm 1\text{sec}$.	AEC-Q200 (MIL-STD-202 Method 210)	32
8	Static Humidity	(1) No physical damage. (2) $ \Delta L_0/L_0 \leq 10\%$	① Preconditioning: Bake at $125 \pm 5^\circ\text{C}$ for $24 \pm 0.5\text{H}$, 245°C Reflow 3 times ② 1000 hours, $85^\circ\text{C}/85\%\text{RH}$. ③ Unpowered. ④ Measurement at 24 ± 4 hours after test conclusion 	AEC-Q200 (MIL-STD-202 Method 103)	77
9	Board Flex	(1) No physical damage. (2) $ \Delta L_0/L_0 \leq 10\%$	① Preconditioning: 245°C Reflow 3 times ② Part mounted on a $100\text{mm} \times 40\text{mm}$ FR4 PCB board, which is $1.6 \pm 0.2\text{mm}$ thick and as a Layer-thickness $35\text{ }\mu\text{m} \pm 10\text{ }\mu\text{m}$. ③ Bending speed is 1mm/s . ④ Keeping the P.C Board 2 mm minimum for 60 seconds.  Unit: mm	AEC-Q200 (AEC-Q200-005)	30
10	Vibration	(1) No physical damage. (2) $ \Delta L_0/L_0 \leq 10\%$	① Preconditioning: 245°C Reflow 3 times ② Frequency range : $10 \sim 2000\text{Hz}$. ③ Amplitude: 1.5mm or 20g . ④ Sweep time and duration: $10 \sim 2000 \sim 10\text{Hz}$ for 20 minutes. ⑤ Each four hours in X,Y,Z direction, 12hours in total.	AEC-Q200 (MIL-STD-202 Method 204)	32
11	Mechanical Shock	(1) No physical damage. (2) $ \Delta L_0/L_0 \leq 10\%$	① Preconditioning: 245°C Reflow 3 times ② Peak acceleration: 100G/S ③ Duration of pulse: 6ms ④ 3times in each of $6(\pm X, \pm Y, \pm Z)$ axes.	AEC-Q200 (MIL-STD-202 Method 213)	32
12	Loading at High Temperature	(1) No physical damage. (2) $ \Delta L_0/L_0 \leq 10\%$	① Preconditioning: Bake at $125 \pm 5^\circ\text{C}$ for $24 \pm 0.5\text{H}$, 245°C Reflow 3 times ② Temperature: $85 \pm 2^\circ\text{C}$. ③ Time : 1000 hours. ④ Applied Current : Rated current. ⑤ Measurement at 24 ± 4 hours after test conclusion	AEC-Q200 (MIL-STD-202 Method 108)	77



Soldering Condition

(This is for recommendation, please customer perform adjustment according to actual application)

Recommend Reflow Soldering Profile : (solder : Sn96.5 / Ag3 / Cu0.5)



Profile Feature	Lead (Pb)-Free solder
Preheat:	
Temperature Min (T_{smin})	150°C
Temperature Max (T_{smax})	200°C
Time (T_{smin} to T_{smax}) (t_s)	60 -120 seconds
Average ramp-up rate: (T_{smax} to T_p)	3°C / second max.
Time maintained above :	
Temperature (T_L)	217°C
Time (t_L)	60-150 seconds
Peak Temperature (T_p)	260°C
Time within $+0_{-5}^{\circ}\text{C}$ of actual peak Temperature (t_p) ²	10 seconds
Ramp-down Rate	6°C/second max.
Time 25°C to Peak Temperature	8minutes max.

Allowed Re-flow times : 2 times

Remark : To avoid discoloration phenomena of chip on terminal electrodes, please use N₂ Re-flow furnace .

